PHOTO RELAY TLP595G

Telecommunication

Data Acquisition

Measurement Instrumentation

The Toshiba TLP595G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a six lead plastic DIP package. The TLP595G is a bi-directional switch which can replace mechanical relays in many applications.

www.DataSheePeak Off-State Voltage : 400V (Min.)

> : 150mA (Max.) (A Connection) On-State Current : 12Ω (Max.) (A Connection) • On-State Resistance

 Isolation Voltage : 2500Vrms (Min.)

· UL Recognized : UL1577, File No. E67349

• Trigger LED Current (Ta = 25°C)

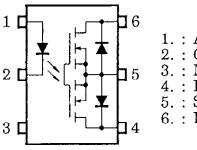
Supplementary Information	Page (s)
Lead Form Options	31-32
Tape and Reel	39-40

7.62 8.64 ± 0.25 65 + 0.1 2.5 MIN. 0.5 7.85~8.80 **JEDEC EIAJ TOSHIBA** 11-9A1

Unit in mm

Weight: 0.49g

Pin Configuration (Top View)



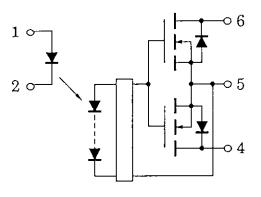
1. : ANODE CATHODE

NC

: DRAIN D1 5. : SOURCE

6. : DRAIN D2

Schematic



The information contained here is subject to change without notice.

The information contained herein is presented only as guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others. These TOSHIBA products are intended for usage in general electronic equipments (office equipment, communication equipment, measuring equipment, domestic electrification, etc.) Please make sure that you consult with us before you use these TOSHIBA products in equipments which require high quality and/or reliability, and in equipments which could have major impact to the welfare of human life (atomic energy control, spaceship, traffic signal, combustion control, all types of safety devices, etc.). TOSHIBA cannot accept liability to any damage which may occur in case these TOSHIBA products were used in the mentioned equipments without prior consultation with TOSHIBA.

	TRIGGER LED C	URRENT (mA)	
CLASSIFICATION (Note 1)	@I _{ON} = 1	50mA	MARKING OF CLASSIFICATION
	MIN.	MAX.	
(IFT2)	_	2	T2
Standard	_	5	T2, Blank

Note 1: Application type name for certification test, please use standard product type name, i.e., TLP595G (IFT2): TLP595G

Maximum Ratings (Ta = 25°C)

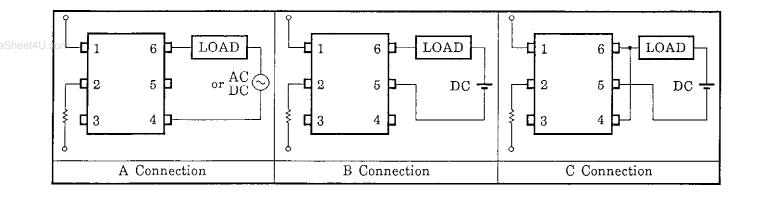
	CHARACTERISTIC			RATING	UNIT	
.DataSheet4U.cor	Forward Current	I _F	30	mA		
	Forward Current Derating (Ta ≥ 25°C)	ΔI _F /°C	-0.3	mA/°C		
LED	Peak Forward Current (100μs pulse, 100pps)		I _{FP}	1	А	
	Reverse Voltage		V _R	5	V	
	Junction Temperature		T _j	125	°C	
	Off-State Output Terminal Voltage		V _{OFF}	400	V	
	On-State RMS Current	A Connection		150		
		B Connection	I _{ON}	200	mA	
DETECTOR		C Connection		300		
DETECTOR		A Connection		-1.5	mA/°C	
	On-State Current Derating (Ta ≥ 25°C)	B Connection	∆l _{ON} /°C	-2.0		
		C Connection		-3.0	1	
	Junction Temperature	•	t _j	125	°C	
Storage Temperature Range			T _{stg}	-55~100	°C	
Operating Temperature Range		T _{opr}	-20~85	°C		
Lead Soldering Temperature (10s)			T _{sol}	260	°C	
Isolation Voltag	e (AC, 1 min., R.H. ≤ 60%)	(Note 2)	BV _S	2500	V _{rms}	

Note 1:Device considered a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 8 shorted together.

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MX.	UNIT
Supply Voltage	V _D	_	_	320	V
Forward Current	l _F	10	15	20	mA
On-State Current	I _{ON}	_	_	150	mA
Operating Temperature	T _{opr}	-20	_	80	°C

Circuit Connections



Individual Electrical Characteristics (Ta = -25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.*	MX.	UNIT
	Forward Voltage	V _F	I _F = 10mA	1.2	1.4	1.7	V
LED	Reverse Current	I _R	V _R = 3V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1MHz	_	15	_	pF
DETECTOR	Off-State Current	I _{OFF}	V _{OFF} = 400V	_	_	1	μΑ
DETECTOR	Capacitance	C _{OFF}	V = 0, f = 1MHz	_	_	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

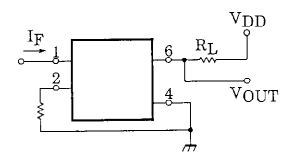
CHARACTER	RISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Trigger LED Current		I _{FT}	I _{ON} = 150mA	_	1	5	mA
	A Connection		I _{ON} = 150mA, I _F = 10mA	_	8	12	
On-State Resistance	B Connection		I _{ON} = 200mA, I _F = 10mA	_	4	6	Ω
	C Connection		I _{ON} = 300mA, I _F = 10mA	_	2	3	

Isolation Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Capacitance Input to Output	C _S	V _S = 0, f = 1MHz	_	0.8	_	pF
Isolation Resistance	R _S	V _S = 500V, R.H. ≤ 60%	5 x 10 ¹⁰	10 ¹⁴	_	Ω
Isolation Voltage	BV _S	AC, 1 minute	2500	_	_	V
		AC, 1 second in oil	_	5000	_	V _{rms}
		DC, 1 minute in oil	_	5000	_	V _{dc}

Switching Characteristics (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MX.	UNIT
Turn-on-Timeom	t _{on}	$V_{DD} = 20 \text{mA}, R_{L} = 200 \Omega$	_	0.3	1.0	ms
Turn-off Time	t _{off}	$I_F = 10 \text{mA}$ (Note 3)	_	0.2	1.0	1115



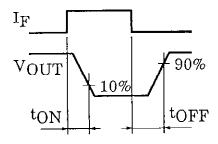
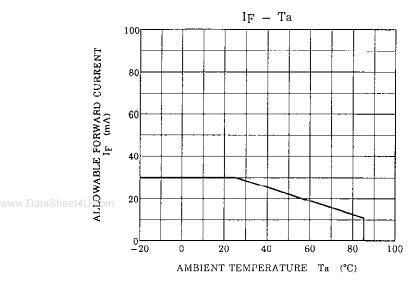
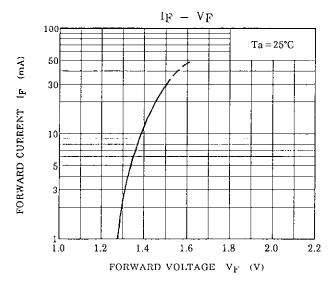
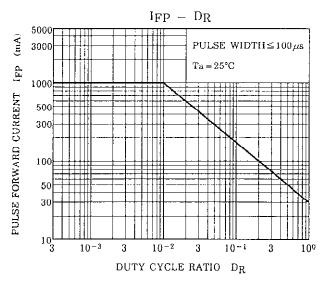
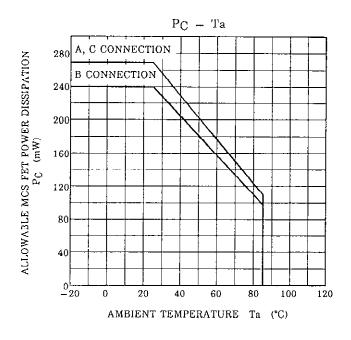


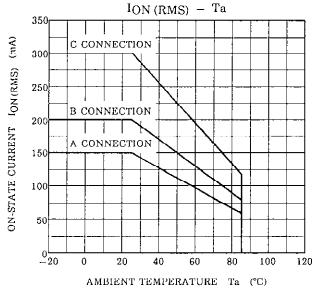
Figure 1. Switching Time Test Circuit

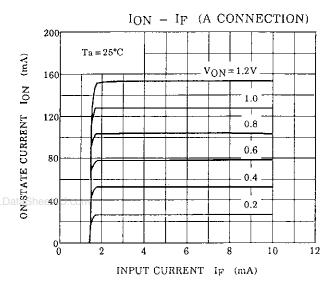


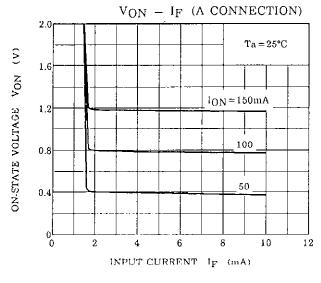


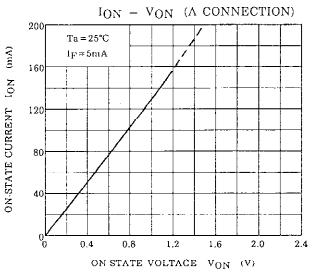


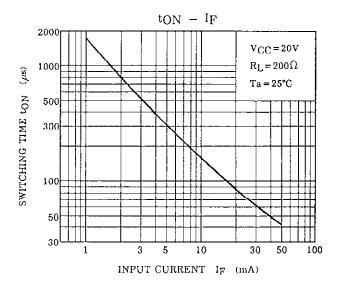


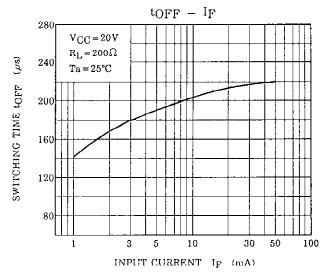




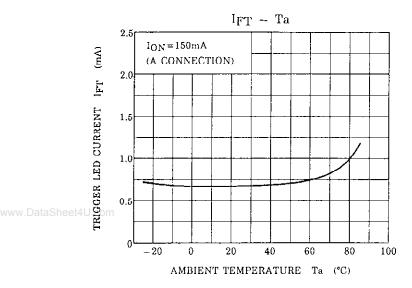


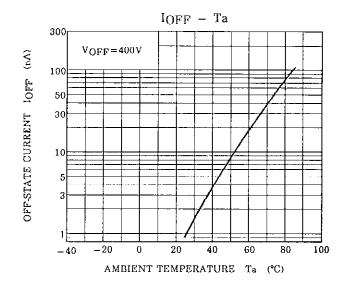


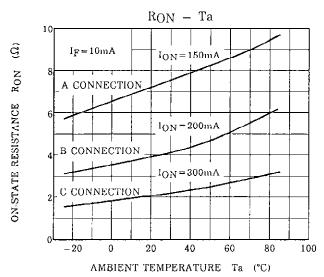


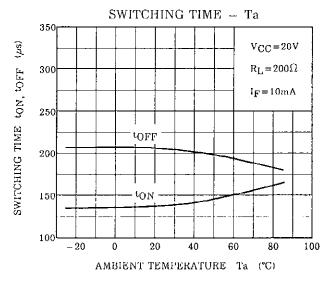


www.DataSheet4U.com









Notes

www DataSheet4U co.